
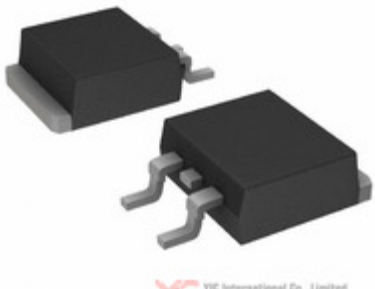








	<p>SQD35N05-26L-GE3</p>
	<p>Hersteller-Teilenummer: SQD35N05-26L-GE3</p> <hr/> <p>Hersteller / Marke: Vishay / Siliconix</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 55V 30A TO252</p> <hr/> <p>Datenblätter:  SQD35N05-26L-GE3.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 15927 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SQD35N05-26L-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 55V 30A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	15927 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	55V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	30A (Tc)
Rds On (Max) @ Id, Vgs	20 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	18nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1175pF @ 25V
Verpackung	Tape & Reel (TR)



















































SQD35N05-26L-GE3 ist neu im Original, Suche SQD35N05-26L-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SQD35N05-26L-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SQD35N05-26L-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SQD35N05-26L-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 55V 30A TO252</p>	 <p>SQD35JA140 SANREX IGBT Modules</p>	 <p>SQD40030E_GE3 Electro-Films (EFI) / Vishay MOSFET N-CHANNEL 40V TO252AA</p>	 <p>SQD40030E_GE3 Vishay / Siliconix MOSFET N-CH 40V TO252AA</p>
 <p>SQD30N05-20L_GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 55V 30A TO252</p>	 <p>SQD40061EL_GE3 Electro-Films (EFI) / Vishay MOSFET P-CHAN 40V</p>	 <p>SQD30N05-20L_GE3 Vishay / Siliconix MOSFET N-CH 55V 30A TO252</p>	 <p>SQD30N05-20L-GE3 V SQD30N05-20L-GE3 V</p>

heiße Teile

Mehr

 SQD200AA60	 SQD200M60	 SQD23N06-31L	 SQD23N06-31L-GE3	 SQD25N06-22L
 SQD25N06-22L-GE3	 SQD25N06-35L-GE3	 SQD25N15-52-GE3	 SQD300A(BA)60	 SQD300A40
 SQD300A60	 SQD300A60E	 SQD300A60F	 SQD300AA100	 SQD300AA100/
 SQD300AA100E	 SQD300AA120	 SQD300AA60	 SQD300BA60	 SQD300H100
 SQD30N05-20L	 SQD30N05-20L-GE3	 SQD35JA140	 SQD35JA160	 SQD35N05-26L-GE3
 SQD400A60	 SQD400A60N	 SQD400A60S	 SQD400A60S/	 SQD400AA-120
 SQD400AA100	 SQD400AA120	 SQD400AA60	 SQD400BA60	 SQD40N04-10A-GE3
 SQD40N06-14L	 SQD40N06-14L-GE3	 SQD40N06-14L_GE3	 SQD40N06-14L_GE3	 SQD40N06-25L-GE3
 SQD40N06-25L-GE3	 SQD40N10-25	 SQD40N10-25-GE3	 SQD40P10-40L-GE3	 SQD45N05-20L-GE3
 SQD45N05-20L-GE3	 SQD45P03-12	 SQD45P03-12-GE3	 SQD50A100	 SQD50A60

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